



High-Slew Operational Amplifier

1 FEATURES

- Low Offset Voltage: ±0.3mV (TYP)
- Low Offset Voltage Drift: ±3.4µV/°C
- High Slew Rate: 24V/µs (TYP)
- High Gain Bandwidth: 10MHz
- Output Short-Circuit Protection
- Supply Voltage: 4.5V to 32V (±2.25V to ±16V)
- Extended Temperature: -40°C to 125°C
- Micro Size Packages: SOT23-5, SOP8, SOP14

2 APPLICATIONS

- Solar Energy: String and Central Inverter
- Motor Drives: AC and Servo Drive Control and Power Stage Modules
- Single Phase Online UPS
- Three Phase UPS
- Pro Audio Mixers
- Battery Test Equipment

3 DESCRIPTIONS

The RS846XP family of devices provide outstanding value for cost-sensitive applications, with features including low offset (±0.3mV, TYP), high slew rate (24 V/ μ s). Integrated EMI and RF filters, and operation across the full -40°C to 125°C enable the RS846XP devices to be used in the most rugged and demanding applications.

The RS846XP is available in Green SOT23-5, SOP8, SOP14 packages. It operates over an ambient temperature range of -40°C to 125°C.

Device information							
PART NUMBER	PACKAGE	BODY SIZE(NOM)					
RS8461P	SOT23-5	2.92mm×1.62mm					
RS8462P	SOP8	4.90mm x 3.90mm					
RS8464P	SOP14	8.65mm x 3.90mm					

Device Information (1)

(1) For all available packages, see the orderable addendum at the end of the data sheet.



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4 REVISION HISTORY

Note: Page numbers for previous revisions may different from page numbers in the current version.

Version	Change Date	Change Item
A.1	2022/10/20	Initial version completed
A.2	2023/06/07	Add RS8461PXF Orderable Device
A.3	2023/06/14	Update PSRR PARAMETER
A.3.1	2024/03/01	Modify packaging naming
A.4	2024/08/01	 Update PACKAGE/ORDERING INFORMATION Update ESD Ratings Delete 8.2 Test Circuit Diagram
A.5	2025/06/13	Add Typical Characteristics Figure 13. Open-Loop Gain and Phase vs Frequency



5 PACKAGE/ORDERING INFORMATION⁽¹⁾

Orderable Device	Package Type	Pin	Channel	Op Temp(°C)	Device Marking ⁽²⁾	MSL ⁽³⁾	Package Qty
RS8461PXF	SOT23-5	5	1	-40°C ~125°C	8461P	MSL3	Tape and Reel, 3000
RS8462PXK	SOP8	8	2	-40°C ~125°C	RS8462P	MSL3	Tape and Reel, 4000
RS8464PXP	SOP14	14	4	-40°C ~125°C	RS8464P	MSL3	Tape and Reel, 4000

NOTE:

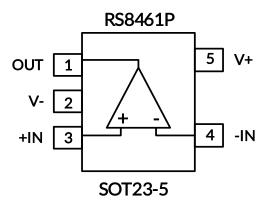
(1) This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.

(2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.

(3) RUNIC classify the MSL level with using the common preconditioning setting in our assembly factory conforming to the JEDEC industrial standard J-STD-20F, Please align with RUNIC if your end application is quite critical to the preconditioning setting or if you have special requirement.



6 PIN CONFIGURATION AND FUNCTIONS



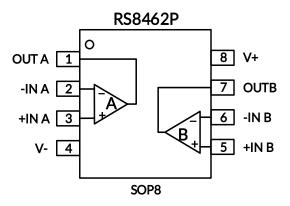
PIN DESCRIPTION

	PIN		
NAME	RS8461P	I/O ⁽¹⁾	DESCRIPTION
	SOT23-5		
-IN	4	I	Negative (inverting) input
+IN	3	I	Positive (noninverting) input
OUT	1	0	Output
V-	2	-	Negative (lowest) power supply
V+	5	-	Positive (highest) power supply

(1) I = Input, O = Output.



PIN CONFIGURATION AND FUNCTIONS



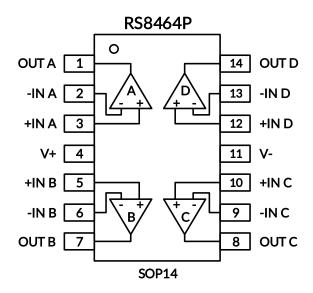
PIN DESCRIPTION

NAME		I/O ⁽¹⁾	DESCRIPTION			
NAME	SOP8	1/0	DESCRIPTION			
-INA	2	I	Inverting input, channel A			
+INA	3	I	Noninverting input, channel A			
-INB	6	I	Inverting input, channel B			
+INB	5	I	Noninverting input, channel B			
OUTA	1	0	Output, channel A			
OUTB	7	0	Output, channel B			
V-	4	-	Negative (lowest) power supply or ground (for single supply operation)			
V+	8	-	Positive (highest) power supply			

(1) I = Input, O = Output.



PIN CONFIGURATION AND FUNCTIONS



PIN DESCRIPTION

	PIN	1(0(1)	DESCRIPTION			
NAME	SOP14	I/O ⁽¹⁾	DESCRIPTION			
-INA	2	I	Inverting input, channel A			
+INA	3	I	Noninverting input, channel A			
-INB	6	I	Inverting input, channel B			
+INB	5	I	Noninverting input, channel B			
-INC	9	I	Inverting input, channel C			
+INC	10	I	Noninverting input, channel C			
-IND	13	I	Inverting input, channel D			
+IND	12	I	Noninverting input, channel D			
OUTA	1	0	Output, channel A			
OUTB	7	0	Output, channel B			
OUTC	8	0	Output, channel C			
OUTD	14	0	Output, channel D			
V-	11	-	Negative (lowest) power supply or ground (for single supply operation)			
V+	4	-	Positive (highest) power supply			

(1) I = Input, O = Output.



7 SPECIFICATIONS

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
Valtaga	Supply, V _S = (V+) - (V-)			36	- V
Voltage	Signal input pin ⁽²⁾		(V-)-0.5	(V+) +0.5	v
Comment	Signal input pin ⁽²⁾		-10	10	mA
Current	Output short-circuits ⁽³⁾		Continuous		
		SOT23-5		230	
ALθ	Package thermal impedance ⁽⁴⁾	SOP8		110	°C/W
			105		
	Operating range, T _A		-40	125	
Temperature	Junction, TJ ⁽⁵⁾		-40	150	°C
	Storage, T _{stg}	-65	150		

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

(2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less.

(3) Short-circuit to ground, one amplifier per package.

(4) The package thermal impedance is calculated in accordance with JESD-51.

(5) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} - T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.

7.2 ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

			VALUE	UNIT
		Human-Body Model (HBM), per ANSI/ESDA/JEDEC JS-001 $^{(1)}$	±2000	
V(ESD)	Electrostatic discharge	Charged-Device Model (CDM), per ANSI/ESDA/JEDEC JS-002 $^{(2)}$	±1500	V
	alsenarge	Machine Model (MM)	±200	

(1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process.



ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Supply yeltage $V_{0,2}(V_{1,1})$	Single-supply	4.5		32	V
Supply voltage, V _S = (V+) - (V-)	Dual-supply	±2.25		±16	v
Operating range, T _A	-40		125	°C	



7.4 Electrical Characteristics

(At T_A=+25°C, V_S=4.5V to 32 V (±2.25V to ±16 V), R_L=10k Ω connected to V_S/2, V_{CM}=V_S/2 and V_{OUT}=V_S/2, Full ⁽⁹⁾=-40°C to 125°C, unless otherwise noted.) ⁽¹⁾

PARAMETER	SYMBOL	CONDITION	TEMP	MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT
INPUT CHARACTERISTICS							
			+25°C	-1	±0.3	1	
Input Offset Voltage	Vos	Vs=±16V, V _{CM} =Vs/2	FULL		±0.36		mV
Input Offset Voltage Average Drift	Vos Tc		FULL		±3.4		μV/°C
Input Bias Current ^{(4) (5)}	1-		+25°C		±10	±60	pА
Input Blas Current (1989)	lв		FULL		±600		pА
Input Offset Current (4)	los		+25°C		±10	±60	pА
	105		FULL		±600		pА
Power-Supply Rejection Ratio	PSRR	V _s =5V~32V, V _{CM} =V _s /2	+25°C	83	101		dB
	FJKK	VS-5V~32V, VCM-VS/Z	FULL		100		uв
Input Common-Mode Voltage Range	V_{CM}		FULL	(V-)		(V+)-2	V
Common Made Paiastian Patia	CMRR	V _S =32V,	+25°C	94	110		dB
Common-Mode Rejection Ratio	CIMIKK	(V-) <v<sub>CM<(V+)-2V</v<sub>	FULL		108		uБ
Open-Loop Voltage Gain	Aol	Vs=32V, RL=10 KΩ	+25°C	101	124		dB
Open-Loop voltage Gain	AOL	V _O =(V-)+0.5V to (V+)-0.5V	FULL		117		
NOISE PERFORMANCE							
Input Voltage Noise	e _{np-p}	f=0.1Hz to 10Hz	+25°C		8.5		μV_{PP}
Input Voltage Noise Density ⁽⁴⁾	en	f=1KHz	+25°C		40		nV/\sqrt{Hz}
DYNAMIC PERFORMANCE							
Slew Rate ⁽⁸⁾	SR	G=+1, V _S =32V	+25°C		24		V/µs
Settling Time to 0.1%	ts	V _S =32V, V _{PP} =7V, G=+1 C _L =100pF	+25°C		1.2		μs
Gain-Bandwidth Product	GBP	Vs=32V, VIN=50mV _{P-P}	+25°C		10		MHz
Overload Recovery Time	tor	V _{IN} × G ≥ V _S	+25°C		0.35		μs
Phase Margin ⁽⁴⁾	φο	Vout=100mV _{P-P} , CL=70pF	+25°C		60		0
OUTPUT CHARACTERISTICS							
Output Voltage Swing from Rail	Vон	Vs=±16V, RL=10 KΩ	+25°C		90	150	mV
	Vol	VS-110V, KL-10 KS2	+25°C		65	150	IIIV
Output Source Current ⁽⁶⁾⁽⁷⁾	I _{SOURCE}	Vs=32V	+25°C	40	75		m 4
Output Sink Current ^{(6) (7)}	I _{sink}	VS-32V	+25 C	40	75		mA
POWER SUPPLY							
Operating Voltage Range	Vs		FULL	4.5		32	V
		Vs=±2.5V, Iout=0mA	+25°C		2.2	4.1	
Quiescent Current Per Amplifier		v 5-±2.3 v, 1001-0111A	FULL			4.5	m^
Quiescent Current Per Amplifier	Ιq	Vs=±16V, Iout=0mA	+25°C		2.6	4.6	mA
		$v_s=\pm 16v$, $l_{OUT}=0mA$	FULL			5.0	
Turn-On Time		Vs=32V	+25°C		52		μs



NOTE:

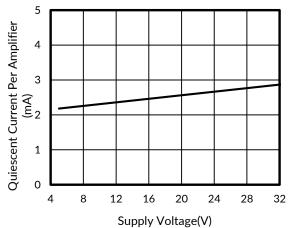
- (1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.
- (2) Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.
- (4) This parameter is ensured by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.
- (6) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.
- (7) Short circuit test is a momentary test.
- (8) Number specified is the slower of positive and negative slew rates.
- (9) Specified by characterization only.



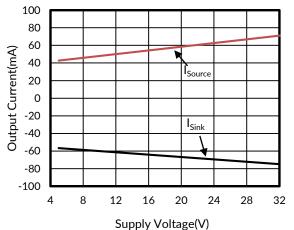
7.5 Typical Characteristics

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, V_S = ±16V, unless otherwise noted.









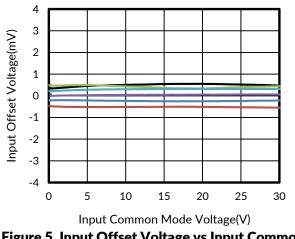


Figure 5. Input Offset Voltage vs Input Common Mode Voltage

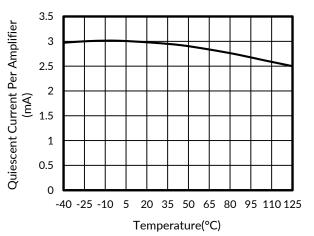


Figure 2. Quiescent Current vs Temperature

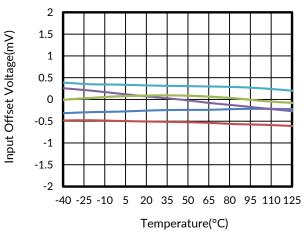


Figure 4. Input Offset Voltage vs Temperature

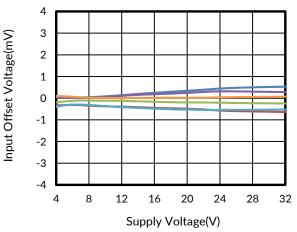


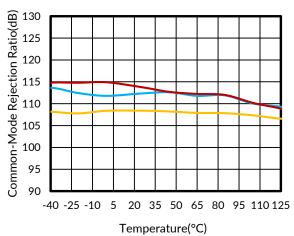
Figure 6. Input Offset Voltage vs Supply Voltage



Typical Characteristics

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, V_S = ±16V, unless otherwise noted.





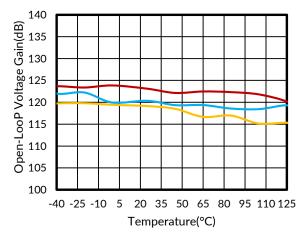
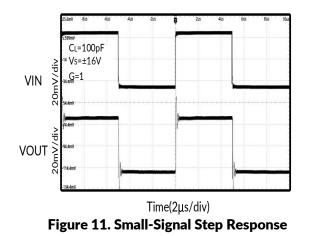


Figure 9. Open-Loop Voltage Gain vs Temperature



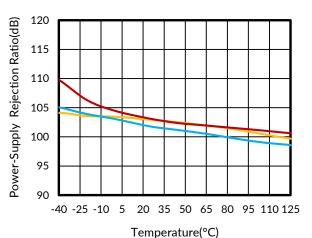


Figure 8. Power-Supply Rejection Ratio vs Temperature

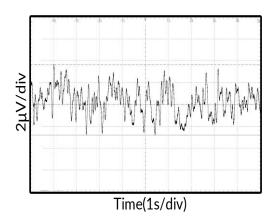
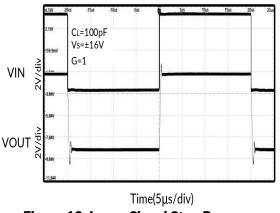


Figure 10. 0.1-Hz to 10-Hz Noise





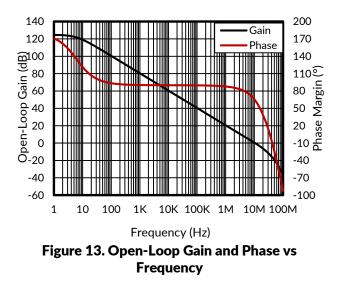




Typical Characteristics

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, V_S = ±16V, unless otherwise noted.





8 DETAILED DESCRIPTION

8.1 Overview

The RS846XP is the next-generation family of the industry standard RS845X high-voltage general purpose amplifiers. These devices provide outstanding value for cost-sensitive applications requiring high slew rate with high voltage signals, such as motor drive and inverter systems.

A robust MUX-friendly input stage enhances flexibility in design, with common-mode voltage range extending to the negative rail as well as improved settling time in multi-channel applications. Low offset voltage (± 0.3 mV, TYP) and low offset voltage drift ($\pm 3.4 \mu$ V/°C) allows the RS846XP family to be used in rugged applications requiring precision current and voltage sensing. High voltage operation (up to 36 V) and high slew rate (24V/ μ s) make the RS846XP family a premier choice for high-voltage applications with fast transients.

8.2 Power Supply Recommendations

Supply voltages larger than 32 V for a single-supply or outside the range of ± 16 V for a dual-supply can permanently damage the device. Place 0.1μ F bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies.

8.3 Slew Rate

The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input. These devices have a $24V/\mu s$ slew rate.

8.4 Device Functional Modes

These devices are powered on when the supply is connected. This device can be operated as a single-supply operational amplifier or dual-supply amplifier depending on the application.



9 APPLICATION AND IMPLEMENTATION

Information in the following applications sections is not part of the RUNIC component specification, and RUNIC does not warrant its accuracy or completeness. RUNIC's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The RS846XP series of operational amplifiers can be used in countless applications. The few applications in this section show principles used in all applications of these parts.

9.2 Inverting Amplifier Application

A typical application for an operational amplifier in an inverting amplifier. This amplifier takes a positive voltage on the input, and makes it a negative voltage of the same magnitude. In the same manner, it also makes negative voltages positive.

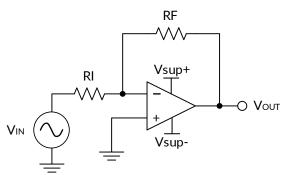


Figure 14. Schematic for Inverting Amplifier Application



10 LAYOUTS

10.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and operational amplifier itself. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
 - Connect low-ESR, 0.1µF ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As shown in Figure 16, keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

10.2 Layout Example

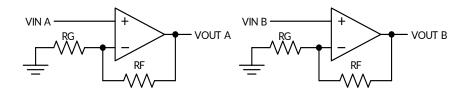
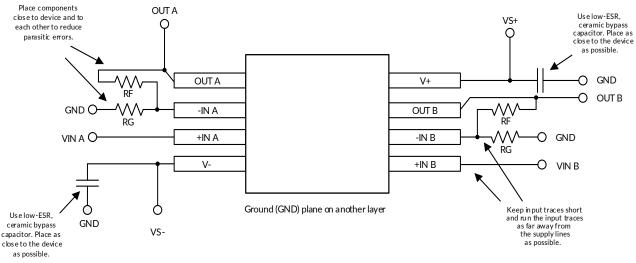


Figure 15. Schematic Representation

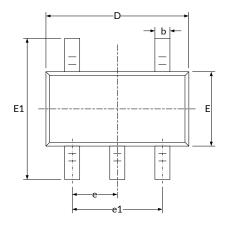


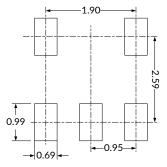


NOTE: Layout Recommendations have been shown for dual op-amp only, follow similar precautions for Single and four.

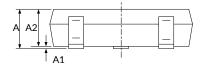


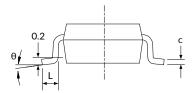
11 PACKAGE OUTLINE DIMENSIONS SOT23-5⁽³⁾





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Min Max		Max	
A ⁽¹⁾	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
с	0.100	0.200	0.004	0.008	
D ⁽¹⁾	2.820	3.020	0.111	0.119	
E ⁽¹⁾	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
e	0.950(BSC) ⁽²⁾	0.037(BSC) ⁽²⁾	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	0°	8°	0°	8°	

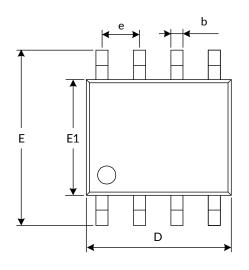
NOTE:

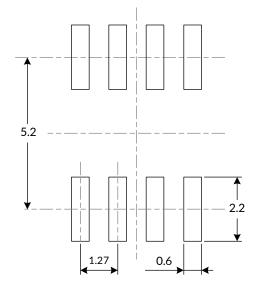
Plastic or metal protrusions of 0.15mm maximum per side are not included.
 BSC (Basic Spacing between Centers), "Basic" spacing is nominal.

3. This drawing is subject to change without notice.

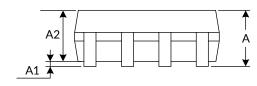


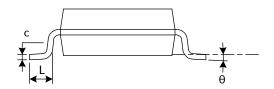
SOP8⁽³⁾





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions I	n Millimeters	Dimensions In Inches			
	Min	Min Max		Max		
A (1)	1.350	1.750	0.053	0.069		
A1	0.100	0.250	0.004	0.010		
A2	1.350	1.550	0.053	0.061		
b	0.330	0.510	0.013	0.020		
с	0.170	0.250	0.007	0.010		
D ⁽¹⁾	4.800	5.000	0.189	0.197		
e	1.270(BSC) ⁽²⁾		0.050(BSC) ⁽²⁾			
E	5.800	6.200	0.228	0.244		
E1 ⁽¹⁾	3.800	4.000	0.150	0.157		
L	0.400	1.270	0.016	0.050		
θ	0°	8°	0°	8°		

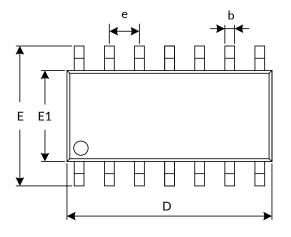
NOTE:

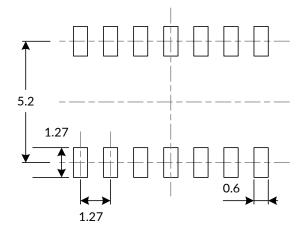
Plastic or metal protrusions of 0.15mm maximum per side are not included.
 BSC (Basic Spacing between Centers), "Basic" spacing is nominal.

3. This drawing is subject to change without notice.

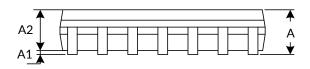


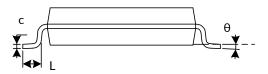
SOP14⁽³⁾





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions I	n Millimeters	Dimensions In Inches			
	Min	Min Max		Мах		
A ⁽¹⁾	1.350	1.750	0.053	0.069		
A1	0.100	0.250	0.004	0.010		
A2	1.350	1.550	0.053	0.061		
b	0.310	0.510	0.012	0.020		
с	0.100	0.250	0.004	0.010		
D ⁽¹⁾	8.450	8.850	0.333	0.348		
e	1.270(BSC) ⁽²⁾		0.050(BSC) ⁽²⁾			
E	5.800	6.200	0.228	0.244		
E1 ⁽¹⁾	3.800	4.000	0.150	0.157		
L	0.400	1.270	0.016	0.050		
θ	0°	8°	0°	8°		

NOTE:

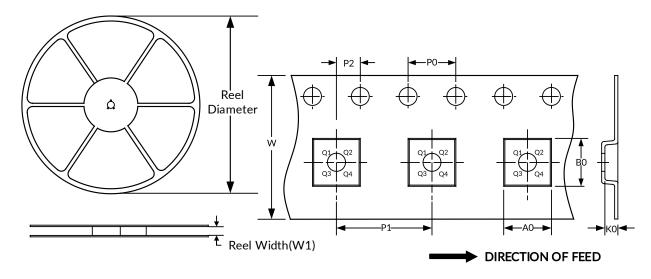
Plastic or metal protrusions of 0.15mm maximum per side are not included.
 BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
 This drawing is subject to change without notice.



12 TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1(mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SOP8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
SOP14	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1

NOTE:

1. All dimensions are nominal.

2. Plastic or metal protrusions of 0.15mm maximum per side are not included.



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